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November 2014

FSA551 Dual SPST Depletion Mode Audio Switch

Features

- Dual SPST
- Depletion Mode Technology
- -3 dB Bandwidth: 240 MHz
- V_{CC-OFF}: 1.5 V to 3.0 V
- V_{CC-ON}: 0 V to 0.2 V
- V_{SW-OFF}: -0.3 V to 3 V .
- V_{SW-ON}: -0.3 V to 3 V
- R_{ON}: 0.38 Ω Typical
- R_{ON} Flat: 0.01 Ω (Typical)
- THD+N: 0.0005% (Typical)
- Fairchild Green, RoHS Compliant, Halogen Free

Description

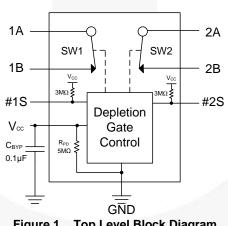
The FSA551 is a high-performance dual single-pole single-throw (SPST x 2) audio switch. The Depletion Mode technology allows the device to conduct signals when there is no V_{CC} available and to isolate signals when V_{cc} is present. During signal conduction, the Depletion Mode gate control allows the FSA551 to achieve excellent THD+N performance while consuming minimal power.

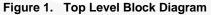
Related Resources

FSA551 Evaluation Board

Applications

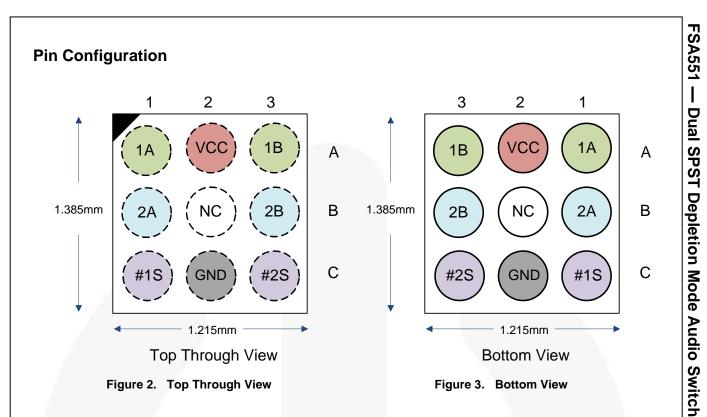
- Smart Phones
- Tablets, Ultra Books





Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FSA551UCX	-40 to 85°C		9-Ball WLCSP, 0.40 mm Pitch, 1.215 x 1.385 x 0.58 mm (Nominal)	3000 Units on Tape & Reel



Pin Descriptions

Pin #	Name	Туре	Description
A1	1A	Depletion I/O	A-Port of Switch 1 (Normally Closed)
A3	1B	Depletion I/O	B-Port of Switch 1 (Normally Closed)
C1	#1S	Control	Select to Enable/Disable SW1 (Enable LOW)
A2	V _{cc}	Power Supply	Power Supply Input
B2	NC	No Connect	Do Not Connect
C2	GND	Ground	Ground
B1	2A	Depletion I/O	A-Port of Switch 2 (Normally Closed)
B3	2B	Depletion I/O	B-Port of Switch 2 (Normally Closed)
C3	#2S	Control	Select to Enable/Disable SW2 (Enable LOW)

Table 1. Depletion Mode Control Truth Table

V _{cc}	#1S	#2S	Switch 1	Switch 2
LOW	Х	Х	ON	ON
HIGH	HIGH	HIGH	OFF	OFF
HIGH	LOW	HIGH	ON	OFF
HIGH	HIGH	LOW	OFF	ON

Table 2. Recommended External Component

Component	Description	Vendor	Parameter	Min.	Тур.	Unit
CBYP	0.1 µF, 10%, 6.3 V, X5R, 0201	Murata GRM033R60J104K	С	0.65	0.1	μF

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
Vcc	Supply/Control Voltage		-0.5	4.6	V
V _{CNTRL}	Control Input Voltage	#1S, #2S	-0.5	4.6	V
V _{SW(ON)}	DC Switch I/O Voltage (Switch Conducting)	1A, 1B, 2A, 2B	-0.5	3.3	V
$V_{\text{SW}(\text{OFF})}$	DC Switch I/O Voltage (Switch Isolated)	1A, 1B, 2A, 2B	-0.5	3.3	V
I _{SW}	Switch I/O Current	V _{CC} =0 V (Switch Conducting)		350	mA
ISWPEAK	Peak Switch Current	Pulsed at 1 ms Duration, <10% Duty Cycle		500	mA
	Human Body Model, ANSI/ESDA/JEDEC	I/O Ports		7	
	JS-001-2012	All Other Pins		5	
ESD	Charged Device Model, JEDEC: JESD22-C101			2	kV
		Contact		8	
	IEC 61000-4-2 System	Air Gap		15	
TA	Absolute Maximum Operating Temperature		-40	+85	°C
Θ_{JA}	Thermal Resistance, Junction-to-Ambient	2S2P JEDEC std. PCB		97	°C/W
T _{STG}	Storage Temperature		-65	+150	°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding these ratings or designing to Absolute Maximum Ratings.

Symbol	Parameter		Min.	Max.	Unit
V _{CC(ON)}	Supply Voltage with Depletion Switch Conducting (14	A=1B; 2A=2B)	0	0.2	V
V _{CC(OFF)}	Supply Voltage with Depletion Switch Isolated (1A≠1)	B; 2A≠2B; #1S=#2S=HIGH)	1.5	3.0	V
V _{SW(ON)}	DC Switch I/O Voltage Sv	Switch Conducting	-0.3	3.0	V
V _{SW(OFF)}	DC Switch I/O Voltage Sv	Switch Isolated	-0.3	3.0	V
V _{CNTRL}	Control Input Voltage #1	1S, #2S	0	3.0	V

FSA551 — Dual SPST Depletion Mode Audio Switch

DC Electrical Characteristics

Unless otherwise specified, typical values are for $T_A=25^{\circ}C$.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =-4	0°C to	+85°C	Unit
• ,		Containen		Min.	Тур.	Max.	•
V _{CC(HYS)}	Supply Voltage Hysteresis				450		mV
I _{ON}	Switch-to-GND Leakage Current (Switch Conducting)	1A=2.6 V, 1B=Float, 2A=2.6 V, 2B=Float	0		0.1	5	μA
I _{OFF}	Switch-to-GND Leakage Current (Switch Isolated)	1A =2.6 V, 1B=GND, 2A=2.6 V, 2B=GND, #1S=#2S=V _{CC}	1.8		0.1	10	μA
I _{CCT}	Increase in I _{CC} per Control Voltage	#1S or #2S=1.2 V	3.0	_	7	15	μA
R _{ON}	Switch On Resistance	I_{SW} =100 mA, V_{SW} =-0.3 V to 3 V	0		0.38	0.60	Ω
ΔR_{ON}	Switch On Resistance Difference, Channel to Channel	$I_{\text{SW}}\text{=}100$ mA, $V_{\text{SW}}\text{=}\text{-}0.3$ V to 3 V	0		0.01		Ω
R _{FLAT(ON)}	On Resistance Flatness	I_{SW} =100 mA, V_{SW} =-0.3 V to 3 V	0		0.01		Ω
R _{PD}	V _{CC} Pull-Down Resistance		<0.2		5.0		MΩ
R _{PU}	Control Pull-Up Resistance		<0.2		3.0		MΩ
	Outland and Sumply Current	Switch Isolated, #1S=#2S=V _{CC}	1.5 - 3.0		70	120	
Icc	Quiescent Supply Current	Switch On	0.2		0.1	0.5	μA
VIH	Select Pin Input High Voltage		1.5 – 3.0	1.2			V
VIL	Select Pin Input Low Voltage		1.5 – 3.0			0.55	V

AC Electrical Characteristics

Unless otherwise specified, typical values are for $T_A=25^{\circ}C$.

Symbol	Deremeter	Condition		T _A =- 4	40°C to ·	+85°C	Uni
Symbol	Parameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	t
t _{ON}	Turn-On Time V _{CC} to Output	$R_L=2 \text{ k}\Omega$, $C_L=10 \text{ pF}$, $V_{SW}=3 \text{ V}$, (Measured 90/10%), Figure 5	1.8 → 0		445		μs
t _{OFF}	Turn-Off Time V _{CC} to Output	$R_L=2 k\Omega$, $C_L=10 pF$, $V_{SW}=3 V$, (Measured 90/10%), Figure 5	0 → 1.8		175		μs
t _{ONS}	Turn-On Time Control Pin	nA=2 kΩ to 2.85 V, nB=1 Ω//10 pF to GND, $\#_n$ S= 1.8 \rightarrow 0 V, (Measured 20/80%), Figure 5	1.8		205		μs
toffs	Turn-Off Time Control Pin	nA=2 kΩ to 2.85 V, nB=1 Ω//10 pF to GND, #nS= 0 → 1.8 V, (Measured 20/80%), Figure 4, Figure 5	1.8		29		μs
Oirra	Port A Off Isolation	$_{n}A=2 k\Omega$ to GND, $_{n}B=1 \Omega$ to GND, # $_{n}S=V_{CC}$, Port B V _{SW} =600 mV _{PP} Ground Referenced, (Measure at f=20 kHz), Figure 7	1.8		-75		dB
O _{irrb}	Port B Off Isolation	$_{n}A=2 k\Omega$ to 2.85 V, $_{n}B=1 \Omega$ to GND, $\#_{n}S=V_{CC}$, Port A V _{DC} + 300 mV _{PP(AC)} , (Measure at f=20 kHz), Figure 6	1.8		-100		dB
BW	-3dB Bandwidth	$R_L=2 k\Omega, C_L=0 pF$	0		240		MHz
THD+N	Total Harmonic Distortion + Noise	$R_L=2 k\Omega$, f=20 Hz to 20 kHz, DC Bias=0 V, V _{SW} =600 mV _{PP} , Measurement BW < 22 kHz	0		0.0005		%

Capacitance

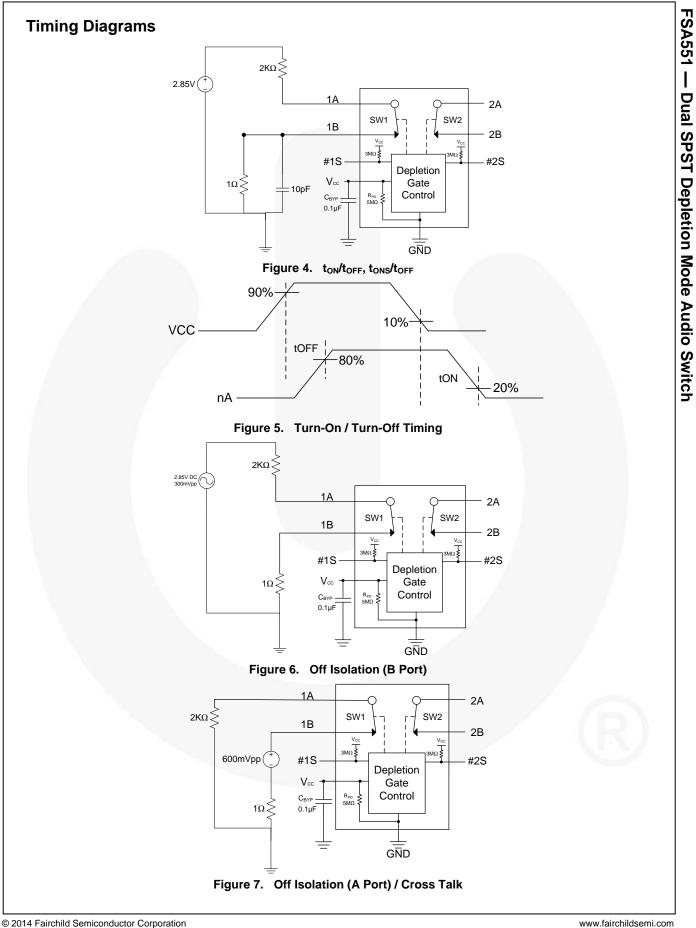
Symbol	Parameter	Condition		Т	= +25°	С	Unit
Symbol	Farameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	Unit
Con	On Capacitance	f=1 MHz, 400 mV _{PP} , 1A, 1B, 2A, 2B	0		21		pF
C _{OFF}	Off Capacitance	f=1 MHz, 400 mV _{PP} , 1A, 1B, 2A, 2B, #1S=#2S=V _{CC}	1.8		25	/	pF
C _{CTRL}	Control Pin Capacitance	f=1 MHz, 400 mV _{PP} , #1S, #2S	1.8		2.5		pF

Oscillator Frequency

Symbol Parameter		Condition			T _A = +25	°C	Unit
Symbol	Parameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	Unit
fosc	Oscillator Frequency ⁽¹⁾	Oscillator Enabled	1.8		775		kHz
f _{OSC%}	Oscillator Frequency Tolerance Over Process & Temperature ⁽¹⁾	Oscillator Enabled	1.8			30	%

Note:

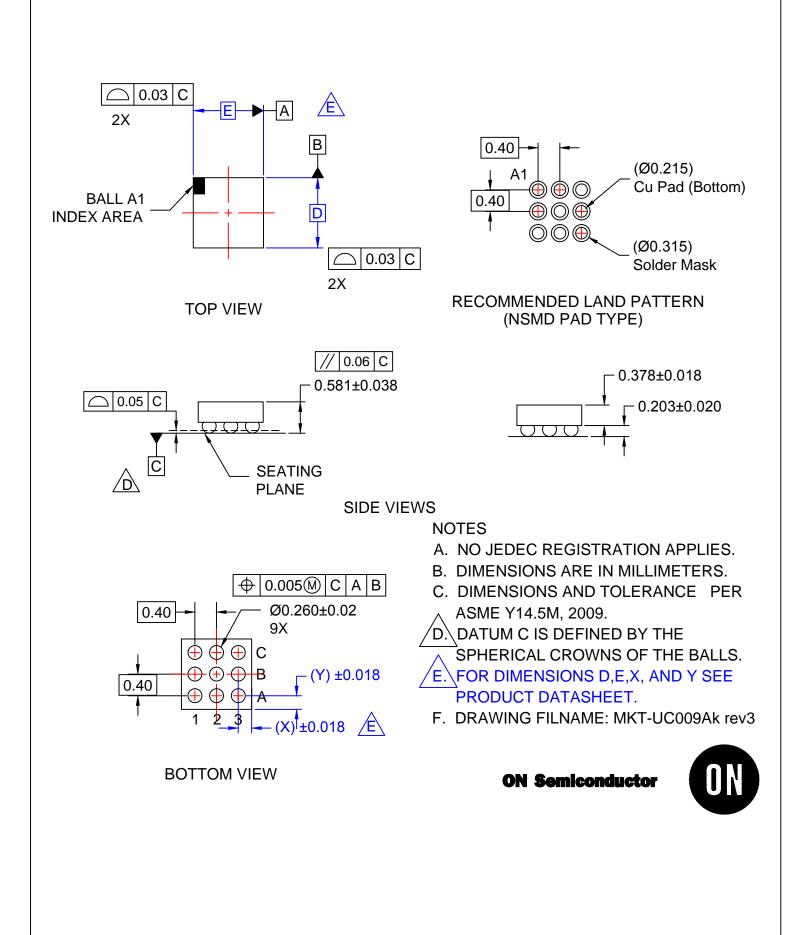
1. Parameters guaranteed by Design and Characterization.



FSA551 • Rev. 1.7

E	nsions D	X	Y
1.215±.03 mm	1.385±.03 mm	0.2075 mm	0.2925 mm

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